ESP32-S3 Series

Datasheet

2.4 GHz Wi-Fi + Bluetooth® LE SoC

Supporting IEEE 802.11b/g/n (2.4 GHz Wi-Fi) and Bluetooth 5 (LE)

Including:

ESP32-S3

ESP32-S3FN8

ESP32-S3R2

ESP32-S3R8

ESP32-S3R8V



Product Overview

ESP32-S3 is a low-power MCU-based SoC that supports 2.4 GHz Wi-Fi and Bluetooth® Low Energy (Bluetooth LE). It consists of high-performance dual-core MCU (Xtensa® 32-bit LX7), a low power coprocessor, a Wi-Fi baseband, a Bluetooth LE baseband, RF module, and peripherals. The block diagram of the SoC is shown below.

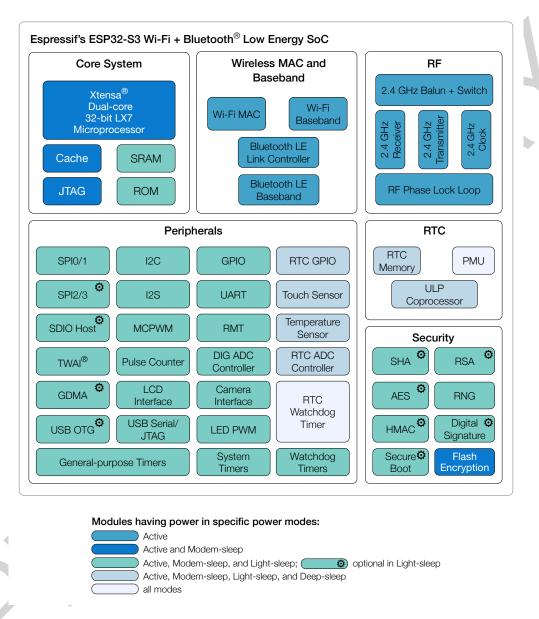


Figure 1: Block Diagram of ESP32-S3

Solution Highlights

- A complete Wi-Fi subsystem that complies with IEEE 802.11b/g/n protocol and supports Station, SoftAP, and SoftAP + Station modes
- A Bluetooth LE subsystem that supports
- features of Bluetooth 5 and Bluetooth mesh
- Xtensa[®] 32-bit LX7 dual-core processor with a five-stage pipeline that operates at up to 240 MHz

- A 128-bit data bus and dedicated SIMD instructions to provide high computing performance
- Efficient L1 cache to improve execution of external memory
- Single-precision floating-point unit (FPU) to accelerate computing
- Highly-integrated RF module that provides industry-leading power and RF performance
- State-of-the-art power management designed for a wide range of applications with its multiple low-power modes. The ULP coprocessor can operate in ultra-low-power mode.
- Powerful storage capacities ensured by 512
 KB SRAM and 384 KB ROM on the chip, and

- SPI, Dual SPI, Quad SPI, Octal SPI, QPI, and OPI interfaces that allow connection to flash and external RAM
- Reliable security features ensured by
 - Cryptographic hardware accelerators that support AES-128/256, Hash, RSA, HMAC, digital signature, and secure boot
 - Random number generator
 - Permission control on accessing internal and external memory
 - External memory encryption and decryption
- Rich set of peripheral interfaces and GPIOs, ideal for various scenarios and complex applications

Features

Wi-Fi

- IEEE 802.11 b/g/n-compliant
- Supports 20 MHz, 40 MHz bandwidth in 2.4 GHz band
- 1T1R mode with data rate up to 150 Mbps
- Wi-Fi Multimedia (WMM)
- TX/RX A-MPDU, TX/RX A-MSDU
- Immediate Block ACK
- Fragmentation and defragmentation
- Automatic Beacon monitoring (hardware TSF)
- 4 × virtual Wi-Fi interfaces
- Simultaneous support for Infrastructure BSS in Station, SoftAP, or Station + SoftAP modes Note that when ESP32-S3 scans in Station mode, the SoftAP channel will change along with the Station channel
- · Antenna diversity
- 802.11mc FTM
- External PA is supported

Bluetooth

- Bluetooth LE: Bluetooth 5, Bluetooth mesh
- High power mode (20 dBm, share the same PA with Wi-Fi)
- 2 Mbps PHY
- Long range mode
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2
- Internal co-existence mechanism between Wi-Fi and Bluetooth to share the same antenna

CPU and Memory

- Xtensa[®] dual-core 32-bit LX7 microprocessor, up to 240 MHz
- CoreMark[®] score:
 - 1 core at 240 MHz: 613.86 CoreMark; 2.56
 CoreMark/MHz
 - 2 cores at 240 MHz: 1181.60 CoreMark;
 4.92 CoreMark/MHz
- 128-bit data bus and SIMD commands

- 384 KB ROM
- 512 KB SRAM
- 16 KB SRAM in RTC
- SPI, Dual SPI, Quad SPI, Octal SPI, QPI and OPI interfaces that allow connection to multiple flash and external RAM
- Flash controller with cache is supported
- Flash in-Circuit Programming (ICP) is supported

Advanced Peripheral Interfaces

- 45 × programmable GPIOs
- Digital interfaces:
 - 4 × SPI
 - 1 x LCD interface (8-bit ~16-bit parallel RGB, I8080 and MOTO6800), supporting conversion between RGB565, YUV422, YUV420 and YUV411
 - 1 × DVP 8-bit ~16-bit camera interface
 - 3 × UART
 - 2 × I2C
 - 2 × I2S
 - 1 × RMT (TX/RX)
 - 1 × pulse counter
 - LED PWM controller, up to 8 channels
 - 1 × full-speed USB OTG
 - 1 × USB Serial/JTAG controller
 - 2 × MCPWM
 - 1 × SDIO host controller with 2 slots
 - DMA controller, with 5 transmit channels and 5 receive channels

- 1 x TWAI[®] controller, compatible with ISO 11898-1 (CAN Specification 2.0)
- Analog interfaces:
 - 2 × 12-bit SAR ADCs, up to 20 channels
 - 1 × temperature sensor
 - 14 × touch sensing IOs
- Timers:
 - 4 × 54-bit general-purpose timers
 - 1 × 52-bit system timer
 - 3 × watchdog timers

Low Power Management

- Power Management Unit with five power modes
- Ultra-Low-Power (ULP) coprocessors:
 - ULP-RISC-V coprocessor
 - ULP-FSM coprocessor

Security

- Secure boot
- Flash encryption
- 4096-bit OTP, up to 1652 bits for users
- Cryptographic hardware acceleration:
 - AES-128/256 (FIPS PUB 197)
 - Hash (FIPS PUB 180-4)
 - RSA
 - Random Number Generator (RNG)
 - HMAC
 - Digital signature

Applications (A Non-exhaustive List)

With low power consumption, ESP32-S3 is an ideal choice for IoT devices in the following areas:

- Smart Home
 - Light control
 - Smart button

- Smart plug
- Industrial Automation
 - Industrial robot

- Mesh network
- Human machine interface (HMI)
- Health Care
 - Health monitor
 - Baby monitor
- Consumer Electronics
 - Smart watch and bracelet
 - Over-the-top (OTT) devices
 - Wi-Fi and bluetooth speaker
 - Logger toys and proximity sensing toys
- Smart Agriculture
 - Smart greenhouse
 - Smart irrigation
 - Agriculture robot
- · Retail and Catering
 - POS machines

- Service robot
- Audio Device
 - Internet music players
 - Live streaming devices
 - Internet radio players
- Generic Low-power IoT Sensor Hubs
- Generic Low-power IoT Data Loggers
- Cameras for Video Streaming
- USB Devices
- Speech Recognition
- Image Recognition
- Wi-Fi + Bluetooth Networking Card
- Touch Sensing
 - Waterproof design
 - Distance sensing applications
 - Linear slider, wheel slider designs

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ESP32-S3 Series Comparison

ESP32-S3 Series Nomenclature

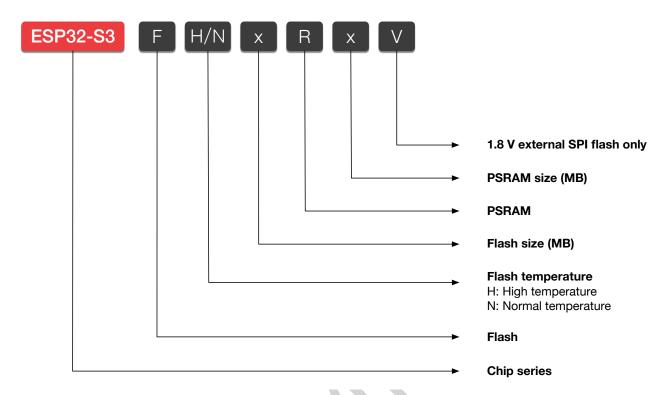


Figure 2: ESP32-S3 Series Nomenclature

1.2 Comparison

Table 1: ESP32-S3 Series Comparison

Ordering Code	SiP flash	SiP PSRAM	Ambient Temperature (°C)	SPI Voltage
ESP32-S3	/ -	_	− 40 ~ 105	3.3 V/1.8 V
ESP32-S3FN8	8 MB (Quad SPI)	_	− 40 ~ 85	3.3 V
ESP32-S3R2		2 MB (Quad SPI)	− 40 ~ 85	3.3 V
ESP32-S3R8	_	8 MB (Octal SPI)	− 40 ~ 85	3.3 V
ESP32-S3R8V	_	8 MB (Octal SPI)	− 40 ~ 85	1.8 V

SiP refers to flash/PSRAM integrated into the package.

Octal SPI occupies five more GPIOs (GPIO33 \sim GPIO37) than Quad SPI.

2. Pin Definition

2.1 Pin Layout

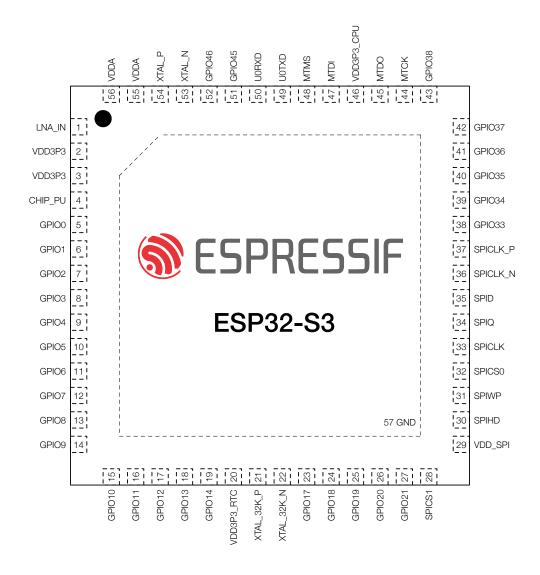




Figure 3: ESP32-S3 Pin Layout (Top View)

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2.2 Pin Description

Table 2: Pin Description

Name	No.	Туре	Power Domain	Function									
LNA_IN	1	I/O		Low Noise Ampli	Low Noise Amplifier(RF LNA) input and output signal								
VDD3P3	2	P_A		Analog power su	Analog power supply								
VDD3P3	3	P_A	+	Analog power su	ıpply								
				High: on, enable	s the chip.								
CHIP_PU	4	I	VDD3P3_RTC	Low: off, the chip	o powers of	f.							
				Note: Do not lea	ve the CHIF	P_PU pin floati	ng.						
GPIO0	5	I/O/T	VDD3P3_RTC	RTC_GPIO0,	GPIO0								
GPIO1	6	I/O/T	VDD3P3_RTC	RTC_GPIO1,	GPIO1,	TOUCH1,	ADC1_CH0						
GPIO2	7	I/O/T	VDD3P3_RTC	RTC_GPIO2,	GPIO2,	TOUCH2,	ADC1_CH1						
GPIO3	8	I/O/T	VDD3P3_RTC	RTC_GPIO3,	GPIO3,	TOUCH3,	ADC1_CH2						
GPIO4	9	I/O/T	VDD3P3_RTC	RTC_GPIO4,	GPIO4,	TOUCH4,	ADC1_CH3						
GPIO5	10	I/O/T	VDD3P3_RTC	RTC_GPIO5,	GPIO5,	TOUCH5,	ADC1_CH4						
GPIO6	11	I/O/T	VDD3P3_RTC	RTC_GPIO6,	GPIO6,	TOUCH6,	ADC1_CH5						
GPIO7	12	I/O/T	VDD3P3_RTC	RTC_GPIO7,	GPIO7,	TOUCH7,	ADC1_CH6						
GPIO8	13	I/O/T	VDD3P3_RTC	RTC_GPIO8,	GPIO8,	TOUCH8,	ADC1_CH7,	SUBSPICS1					
GPIO9	14	I/O/T	VDD3P3_RTC	RTC_GPIO9,	GPIO9,	TOUCH9,	ADC1_CH8,	SUBSPIHD,	FSPIHD				
GPIO10	15	I/O/T	VDD3P3_RTC	RTC_GPIO10,	GPI010,	TOUCH10,	ADC1_CH9,	FSPIIO4,	SUBSPICSO,	FSPICS0			
GPIO11	16	I/O/T	VDD3P3_RTC	RTC_GPIO11,	GPI011,	TOUCH11,	ADC2_CH0,	FSPIIO5,	SUBSPID,	FSPID			
GPIO12	17	I/O/T	VDD3P3_RTC	RTC_GPIO12,	GPI012,	TOUCH12,	ADC2_CH1,	FSPIIO6,	SUBSPICLK,	FSPICLK			
GPIO13	18	I/O/T	VDD3P3_RTC	RTC_GPIO13,	GPI013,	TOUCH13,	ADC2_CH2,	FSPIIO7,	SUBSPIQ,	FSPIQ			
GPIO14	19	I/O/T	VDD3P3_RTC	RTC_GPIO14,	GPIO14,	TOUCH14,	ADC2_CH3,	FSPIDQS,	SUBSPIWP,	FSPIWP			
VDD3P3_RTC	20	P_A	_	Analog power su	ıpply								
XTAL_32K_P	21	I/O/T	VDD3P3_RTC	RTC_GPIO15,	GPIO15,	U0RTS,	ADC2_CH4,	XTAL_32K_P					
XTAL_32K_N	22	I/O/T	VDD3P3_RTC	RTC_GPIO16,	GPIO16,	U0CTS,	ADC2_CH5,	XTAL_32K_N					
GPIO17	23	I/O/T	VDD3P3_RTC	RTC_GPIO17,	GPI017,	U1TXD,	ADC2_CH6						
GPIO18	24	I/O/T	VDD3P3_RTC	RTC_GPIO18,	GPIO18,	U1RXD,	ADC2_CH7,	CLK_OUT3					

Name	No.	Type	Power Domain	Function					
GPIO19	25	I/O/T	VDD3P3_RTC	RTC_GPIO19,	GPI019,	U1RTS,	ADC2_CH8,	CLK_OUT2,	USB_D-
GPIO20	26	I/O/T	VDD3P3_RTC	RTC_GPIO20,	GPIO20,	U1CTS,	ADC2_CH9,	CLK_OUT1,	USB_D+
GPIO21	27	1/0/T	VDD3P3_RTC	RTC_GPIO21,	GPIO21				
SPICS1	28	I/O/T	VDD_SPI	SPICS1,	GPIO26				
VDD_SPI	29	P_D		Output power su	pply: 1.8 V	or VDD3P3_F	TC		
SPIHD	30	I/O/T	VDD_SPI	SPIHD,	GPIO27				
SPIWP	31	I/O/T	VDD_SPI	SPIWP,	GPIO28				
SPICS0	32	I/O/T	VDD_SPI	SPICS0,	GPIO29				
SPICLK	33	I/O/T	VDD_SPI	SPICLK,	GPIO30				
SPIQ	34	I/O/T	VDD_SPI	SPIQ,	GPIO31				
SPID	35	I/O/T	VDD_SPI	SPID,	GPIO32				
SPICLK_N	36	I/O/T	VDD_SPI	SPICLK_N_DIFF,	GPIO48,	SUBSPICLK	_N_DIFF		
SPICLK_P	37	I/O/T	VDD_SPI	SPICLK_P_DIFF,	GPI047,	SUBSPICLK	_P_DIFF		
GPIO33	38	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO4,	GPIO33,	FSPIHD,	SUBSPIHD		
GPIO34	39	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO5,	GPIO34,	FSPICS0,	SUBSPICS0		
GPIO35	40	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO6,	GPIO35,	FSPID,	SUBSPID		
GPIO36	41	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO7,	GPIO36,	FSPICLK,	SUBSPICLK		
GPIO37	42	I/O/T	VDD3P3_CPU / VDD_SPI	SPIDQS,	GPIO37,	FSPIQ,	SUBSPIQ		
GPIO38	43	I/O/T	VDD3P3_CPU	GPIO38,	FSPIWP,	SUBSPIWP			
MTCK	44	I/O/T	VDD3P3_CPU	MTCK,	GPIO39,	CLK_OUT3,	SUBSPICS1		
MTDO	45	I/O/T	VDD3P3_CPU	MTDO,	GPIO40,	CLK_OUT2			
VDD3P3_CPU	46	P_D	_	Input power supp	oly for CPU	10			
MTDI	47	I/O/T	VDD3P3_CPU	MTDI,	GPI041,	CLK_OUT1			
MTMS	48	I/O/T	VDD3P3_CPU	MTMS,	GPIO42				
U0TXD	49	I/O/T	VDD3P3_CPU	U0TXD,	GPIO43,	CLK_OUT1			
U0RXD	50	I/O/T	VDD3P3_CPU	U0RXD,	GPI044,	CLK_OUT2			
GPIO45	51	I/O/T	VDD3P3_CPU	GPIO45					
GPIO46	52	I/O/T	VDD3P3_CPU	GPIO46					
XTAL_N	53		_	External crystal o	utput				

Name	No.	Туре	Power Domain	Function
XTAL_P	54		_	External crystal input
VDDA	55	P_A	\	Analog power supply
VDDA	56	P_A		Analog power supply
GND	57	G		Ground

Pin Definition

 $^{^{1}}$ P: power pin; P $_{A}$: analog power pin; P $_{D}$: digital power pin; I: input; O: output; T: high impedance.

² Pin functions in bold font are the default pin functions.

³ Power supply for GPIO33, GPIO34, GPIO35, GPIO36 and GPIO37 is configurable to be either VDD3P3_CPU (default) or VDD_SPI.

⁴ The pin function in this table refers only to some fixed settings and do not cover all cases for signals that can be input and output through the GPIO matrix. For more information on the GPIO matrix, please refer to ESP32-S3 Technical Reference Manual.

Pin Name Description 2.3

The explanation of each pin name is briefly described below.

Table 3: Pin Name Description

Pin Name	Description
	General-purpose input and output (x is GPIO number). GPIO pins can
GPIOx	be assigned various functions, including digital and analog functions. For
	more information on digital functions, please refer to Table 5.
SPIx	SiP flash/PSRAM and external flash/RAM interface (x is CLK, CS0, CS1,
SPIX	D, Q, WP, HD, IO4~7 or DQS).
XTAL_32K_P/N	32 KHz external clock input/output (connecting to ESP32-S3's oscillator).
ATAL_SZK_F/IN	P/N means differential clock positive/negative.
XTAL_P/N	External clock input/output (connecting to ESP32-S3's oscillator). P/N
ATAL_F/IN	means differential clock positive/negative.
U0RXD/U0TXD	UART0 receive/transmit signals.
MTCK/MTDO/MTDI/MTMS	JTAG interface signals.
LNA_IN	Low-Noise Amplifier (RF LNA) input/output signals.
CHIP_PU	Chip power up pin.
GND	External ground connection.
VDDA	Power supply for analog domain.
VDD3P3_RTC	Power supply for RTC digital domain.
VDD3P3_CPU	Power supply for digital domain.
VDD_SPI	Power supply for SPI IOs.

Function Name Description

The explanation of each function name is briefly described below.

Table 4: Function Name Description

Function Name	Description
RTC_GPIOx	RTC domain GPIO function for low power management.
TOUCHX	Analog function for touch sensing.
ADCx_CHy	Analog to digital conversion channel (x is ADC number, y is channel number).
SUBSPIX	Sub-SPI0/1 bus, differing from SPIx bus (x is CLK, CS0, CS1, D, Q, WP or HD),
SUBSPIX	used for different voltage level of flash and PSRAM
FSPIx	8-line Fast-SPI2 bus function (x is CLK, CS0, CS1, D, Q, WP, HD, IO4~7 or DQS)
SPIx	SPI0/1 bus function (x is CLK, CS0, CS1, D, Q, WP, HD, IO4~7 or DQS)
UxRTS/UxCTS	UARTx hardware flow control signals (x is UART number).
U1RXD/U1TXD	UART1 receive/transmit signals.
CLK_OUTx	Clock output for debug (x is clock number).
USB D-/USB D+	USB OTG and USB Serial/JTAG function. USB signal is a differential signal
036_0-7036_0+	transmitted over a pair of D+ and D- wires.
SPICLK_N/P_DIFF	Serial peripheral interface differential clock negative/positive.

Pin Definition

2.5 GPIO Functions

ESP32-S3 has 45 GPIO pins (numbering 22-25 is not used) which can be assigned various functions as listed in Table 5. The functions listed here are digital functions (F0-F4). RTC functions and analog functions can be found in Table 2.

Table 5: GPIO Functions

GPIO	Pin Name	F0	Туре	F1	Туре	F2	Туре	F3	Туре	F4	Туре	At Reset	After Reset	Notes
0	GPIO0	GPIO0	I/O/T	GPI00	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	R
1	GPIO1	GPIO1	I/O/T	GPIO1	I/O/T	-	-	-	-	-	-	IE1	IE1	R
2	GPIO2	GPIO2	I/O/T	GPIO2	I/O/T	A	-	-	-	-	-	IE1	IE1	R
3	GPIO3	GPIO3	I/O/T	GPIO3	I/O/T	-	-	-	-	-	-	IE1	IE1	R
4	GPIO4	GPIO4	I/O/T	GPIO4	I/O/T	-	-	-	-	-	-	IE0	IE0	R
5	GPIO5	GPIO5	I/O/T	GPIO5	I/O/T	-	-	-	-	-	-	IE0	IE0	R
6	GPIO6	GPIO6	I/O/T	GPIO6	I/O/T	-	-	-	-	-	-	IE0	IE0	R
7	GPIO7	GPIO7	I/O/T	GPIO7	I/O/T	-	-	-	-	-	-	IE0	IE0	R
8	GPIO8	GPIO8	I/O/T	GPIO8	I/O/T	-	-	SUBSPICS1	O/T	-	-	IE0	IE0	R
9	GPIO9	GPIO9	I/O/T	GPIO9	I/O/T	-	-//	SUBSPIHD	I1/O/T	FSPIHD	I1/O/T	IE0	IE1	R
10	GPIO10	GPIO10	I/O/T	GPIO10	I/O/T	FSPIIO4	11/O/T	SUBSPICS0	O/T	FSPICS0	I1/O/T	IE0	IE1	R
11	GPIO11	GPIO11	I/O/T	GPIO11	I/O/T	FSPIIO5	11/O/T	SUBSPID	I1/O/T	FSPID	I1/O/T	IE0	IE1	R
12	GPIO12	GPIO12	I/O/T	GPIO12	I/O/T	FSPIIO6	11/O/T	SUBSPICLK	O/T	FSPICLK	I1/O/T	IE0	IE1	R
13	GPIO13	GPIO13	I/O/T	GPIO13	I/O/T	FSPIIO7	11/O/T	SUBSPIQ	11/O/T	FSPIQ	I1/O/T	IE0	IE1	R
14	GPIO14	GPIO14	I/O/T	GPIO14	I/O/T	FSPIDQS	O/T	SUBSPIWP	I1/O/T	FSPIWP	I1/O/T	IE0	IE1	R
15	XTAL_32K_P	GPIO15	I/O/T	GPIO15	I/O/T	U0RTS	0	-	-	-	-	IE0	IE0	R
16	XTAL_32K_N	GPIO16	I/O/T	GPIO16	I/O/T	U0CTS	I1	-	-	-	-	IE0	IE0	R
17	GPIO17	GPIO17	I/O/T	GPIO17	I/O/T	U1TXD	0	-	-	-	-	IE0	IE1	R
18	GPIO18	GPIO18	I/O/T	GPIO18	I/O/T	U1RXD	I1	CLK_OUT3	0	-	-	IE0	IE1	R
19	GPIO19	GPIO19	I/O/T	GPIO19	I/O/T	U1RTS	0	CLK_OUT2	0	-	-	IE0	IE0	R
20	GPIO20	GPIO20	I/O/T	GPIO20	I/O/T	U1CTS	I1	CLK_OUT1	0	-	-	IE0	IE0	R
21	GPIO21	GPIO21	I/O/T	GPIO21	I/O/T	-	-	-	-	-	-	IE0	IE0	R
26	SPICS1	SPICS1	O/T	GPIO26	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
27	SPIHD	SPIHD	I1/O/T	GPIO27	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
28	SPIWP	SPIWP	I1/O/T	GPIO28	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
29	SPICS0	SPICS0	O/T	GPIO29	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-

GPIO	Pin Name	F0	Туре	F1	Туре	F2	Туре	F3	Type	F4	Туре	At Reset	After Reset	Notes
30	SPICLK	SPICLK	О/Т	GPIO30	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
31	SPIQ	SPIQ	I1/O/T	GPIO31	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
32	SPID	SPID	11/O/T	GPIO32	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
33	GPIO33	GPIO33	I/O/T	GPIO33	I/O/T	FSPIHD	I1/O/T	SUBSPIHD	I1/O/T	SPIIO4	I1/O/T	IE0	IE1	-
34	GPIO34	GPIO34	I/O/T	GPIO34	I/O/T	FSPICS0	I1/O/T	SUBSPICS0	O/T	SPIIO5	I1/O/T	IE0	IE1	-
35	GPIO35	GPIO35	I/O/T	GPIO35	I/O/T	FSPID	I1/O/T	SUBSPID	I1/O/T	SPIIO6	I1/O/T	IE0	IE1	-
36	GPIO36	GPIO36	I/O/T	GPIO36	I/O/T	FSPICLK	I1/O/T	SUBSPICLK	O/T	SPIIO7	I1/O/T	IE0	IE1	-
37	GPIO37	GPIO37	I/O/T	GPIO37	I/O/T	FSPIQ	I1/O/T	SUBSPIQ	I1/O/T	SPIDQS	10/O/T	IE0	IE1	-
38	GPIO38	GPIO38	I/O/T	GPIO38	I/O/T	FSPIWP	I1/O/T	SUBSPIWP	I1/O/T	-	-	IE0	IE1	-
39	MTCK	MTCK	11	GPIO39	I/O/T	CLK_OUT3	0	SUBSPICS1	О/Т	-	-	IE0	IE1, or IE1&WPU1	-
40	MTDO	MTDO	O/T	GPIO40	I/O/T	CLK_OUT2	0	-	-	-	-	IE0	IE1	-
41	MTDI	MTDI	l1	GPIO41	I/O/T	CLK_OUT1	0	-	-	-	-	IE0	IE1	-
42	MTMS	MTMS	l1	GPIO42	I/O/T	-	-	-	-	-	-	IE0	IE1	-
43	U0TXD	U0TXD	0	GPIO43	I/O/T	CLK_OUT1	0	-	-	-	-	IE1, WPU1	IE1, WPU1	-
44	U0RXD	U0RXD	l1	GPIO44	I/O/T	CLK_OUT2	0	-	-	-	-	IE1, WPU1	IE1, WPU1	-
45	GPIO45	GPIO45	I/O/T	GPIO45	I/O/T	-	-	-	-	-	-	IE1, WPD1	IE1, WPD1	-
46	GPIO46	GPIO46	I/O/T	GPIO46	I/O/T	-	-	- /	-	-	-	IE1, WPD1	IE1, WPD1	-
47	SPICLK_P	SPICLK_P_DIFF	О/Т	GPIO47	I/O/T	SUBSPI- CLK_P_DIFF	О/Т	-	-	-	-	IE1	IE1	-
48	SPICLK_N	SPICLK_N_DIFF	О/Т	GPIO48	I/O/T	SUBSPI- CLK_N_DIFF	О/Т	-	-	-	-	IE1	IE1	-

10

Pin Definition

Please refer to the next page for more information on GPIO functions.

Type

Each digital function (Fn, n=0~4) is associated with a "Type". The description of "Type" is as follows:

- O: Output only.
- O/T: The signal can be output or high-impedance.
- I/O/T: The signal can be input, output, and high-impedance.
- I1: Input only. If the pin is assigned a function other than Fn, the input signal of Fn is always "1".
- I1/O/T: The signal can be input, output, and high-impedance. If Fn is not selected, the input signal of Fn is always "1".
- I0/O/T: The signal can be input, output, and high-impedance. If Fn is not selected, the input signal of Fn is

At Reset/After Reset

The default configuration of each pin at reset and after reset:

- IEO input disabled
- IE1 input enabled
- IE1, WPD1 input enabled, internal weak pull-down resistor enabled
- IE1, WPU1 input enabled, internal weak pull-up resistor enabled
- IE1, or IE1&WPU1 When the value of eFuse bit EFUSE_DIS_PAD_JTAG is
 - 1, the MTCK pin floats after chip reset (IE1)
 - 0, the MTCK pin connects to internal weak pull-up resistor after chip reset (IE1&WPU1)

Notes

• R - These pins have RTC or analog functions.

Drive Strength

- The default drive strength of GPIO27~32 is 2'd3 (~40 mA).
- The default drive strength of other pins is 2'd2 (~20 mA).

Pin-to-Pin Mapping Between Chip and SiP Flash/PSRAM

Table 6 lists the pin-to-pin mapping between the chip and the SiP flash/PSRAM. The chip pins listed here are not recommended for other usage. For the data port connection between ESP32-S3 and external flash please refer to Section 3.4.2.

Table 6: Pin-to-Pin Mapping Between Chip and SiP Flash/PSRAM

ESP32-S3FN8	SiP flash (8 MB, Quad SPI)	
SPICLK	CLK	
SPICS0	CS#	
SPID	DI	
SPIQ	DO	
SPIWP	WP#	
SPIHD	HOLD#	
ESP32-S3R2	SiP PSRAM (2 MB, Quad SPI)	

SPICLK	CLK	
SPICS1	CE#	
SPID	SI/SIO0	
SPIQ	SO/SIO1	
SPIWP	SIO2	
SPIHD	SIO3	
ESP32-S3R8 / ESP32-S3R8V	SiP PSRAM (8 MB, Octal SPI)	
SPICLK	CLK	
SPICS1	CE#	
SPID	DQ0	
SPIQ	DQ1	
SPIWP	DQ2	
SPIHD	DQ3	
GPIO33	DQ4	
GPIO34	DQ5	
GPIO35	DQ6	
GPIO36	DQ7	
GPIO37	DQS/DM	

2.7 Power Scheme

ESP32-S3 has four input power pins:

- VDDA1
- VDDA2
- VDD3P3 RTC
- VDD3P3 CPU

And one input/output power pin:

• VDD_SPI

VDDA1 and VDDA2 are the input power supply for the analog domain.

VDD_SPI can be an input power supply or output power supply. It can be powered by Flash Voltage Regulator (nominal 1.8 V) or by VDD3P3_RTC via R_{SPI} (nominal 3.3 V). As the SiP flash/PSRAM in ESP32-S3FN8, ESP32-S3R2, and ESP32-S3R8 operates at 3.3 V, VDD_SPI must be powered by VDD3P3_RTC via R_{SPI} . Software can power off VDD_SPI to minimize current leakage of flash in Deep-sleep mode.

VDD3P3_RTC is the input power supply for Low Power Voltage Regulator that powers the RTC domain.

VDD3P3_CPU and VDD3P3_RTC power Digital System Voltage Regulator at the same time that further powers the Digital System domain.

VDD3P3_RTC is the input power supply for RTC IO.

VDD3P3_CPU is the input power supply for Digital IO.

VDD_SPI is the input power supply for SPI IO.

Either VDD_SPI or VDD3P3_CPU can be selected as the input power supply for SPI/Digital IO.

The power scheme diagram is shown in Figure 4.

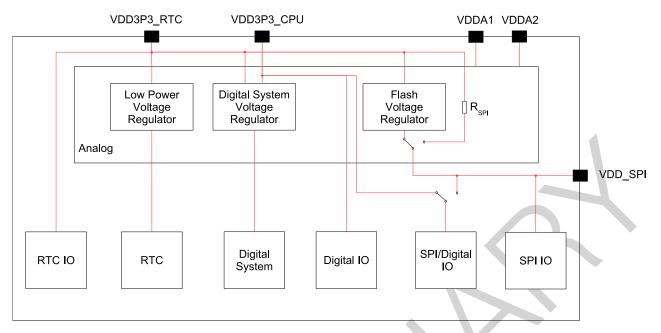


Figure 4: ESP32-S3 Power Scheme

Notes on CHIP_PU:

Figure 5 shows the power-up and reset timing of ESP32-S3 series. Details about the parameters are listed in Table 7.

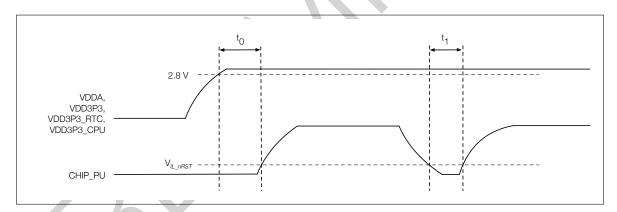


Figure 5: ESP32-S3 Power-up and Reset Timing

Table 7: Description of ESP32-S3 Power-up and Reset Timing Parameters

1	Parameter	Description		
		Time between bringing up the VDDA, VDD3P3, VDD3P3_RTC, and	50	
l to	VDD3P3_CPU rails, and activating CHIP_PU			
Ī	+	Duration of CHIP_PU signal level $<$ V_{IL_nRST} (refer to its value in	50	
l ₁	Table 16) to reset the chip	50		

2.8 Strapping Pins

ESP32-S3 has four strapping pins:

- GPI00
- GPIO45
- GPIO46
- GPIO3

Software can read the values of corresponding bits from register "GPIO_STRAPPING".

During the chip's system reset (power-on-reset, RTC watchdog reset, brownout reset, analog super watchdog reset, and crystal clock glitch detection reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down.

GPIO0, GPIO45 and GPIO46 are connected to the chip's internal weak pull-up/pull-down during the chip reset. Consequently, if they are unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of these strapping pins.

GPIO3 is floating by default. Its strapping value can be configured to determine the source of the JTAG signal inside the CPU, as shown in Table 9. In this case, the strapping value is controlled by the external circuit that cannot be in a high impedance state. Table 8 shows more configuration combinations of EFUSE_DIS_USB_JTAG, EFUSE_DIS_PAD_JTAG, and EFUSE_STRAP_JTAG_SEL that determine the JTAG signal source.

EFUSE_STRAP_JTAG_SEL EFUSE_DIS_USB_JTAG EFUSE_DIS_PAD_JTAG JTAG Signal Source 0 Refer to Table 9 0 Ω 0 0 USB Serial/JTAG controller 0 USB Serial/JTAG controller don't care 1 1 0 don't care On-chip JTAG pins don't care 1 1 N/A

Table 8: JTAG Signal Source Selection

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32-S3.

After reset, the strapping pins work as normal-function pins.

Refer to Table 9 for a detailed configuration of the strapping pins.

Table 9: Strapping Pins

VDD SPI Voltage 1

VDD_SPI Voltage ¹			
Pin	Default	3.3 V	1.8 V
GPIO45	Pull-down	0	1
Booting Mode ²			
Pin	Default	SPI Boot	Download Boot
GPIO0	Pull-up	1	0
GPIO46	Pull-down	Don't care	0
Enabling/Disabling ROM Messages Print During Booting ³ ⁴			
Pin	Default	Enabled	Disabled
GPIO46	Pull-down	See the fourth note	See the fourth note
JTAG Signal Selection			

Pin Default		EFUSE_DIS_USB_JTAG = 0, EFUSE_DIS_PAD_JTAG = 0,	
FIII	Delault	EFUSE_STRAP_JTAG_SEL=1	
GPIO3	N/A	0: JTAG signal from on-chip JTAG pins	
		1: JTAG signal from USB Serial/JTAG controller	

Note:

- 1. VDD_SPI voltage is determined either by the strapping value of GPIO45 or by VDD_SPI_TIEH. When EFUSE_VDD_SPI_FORCE is 0, VDD_SPI voltage is determined by the strapping value of GPIO45; when EFUSE_VDD_SPI_FORCE is 1, VDD_SPI voltage is determined by VDD_SPI_TIEH.
- 2. The strapping combination of GPIO46 = 1 and GPIO0 = 0 is invalid and will trigger unexpected behavior.
- 3. ROM boot messages can be printed over U0TXD (by default) or GPI017 (U1TXD), depending on the eFuse bit EFUSE_UART_PRINT_CHANNEL.
- 4. When both EFUSE_DIS_USB_SERIAL_JTAG and EFUSE_DIS_USB_OTG are 0, ROM boot messages will be printed to the USB Serial/JTAG controller. Otherwise, the messages will be printed to UART, controlled by GPIO46 and EFUSE_UART_PRINT_CONTROL. Specifically, when EFUSE_UART_PRINT_CONTROL value is:
 - 0, print is normal during boot and not controlled by GPIO46.
 - 1 and GPIO46 is 0, print is normal during boot; but if GPIO46 is 1, print is disabled.
 - 2 and GPIO46 is 0, print is disabled; but if GPIO46 is 1, print is normal.
 - 3, print is disabled and not controlled by GPIO46.

Figure 6 shows the setup and hold times for the strapping pin before and after the CHIP_PU signal goes high. Details about the parameters are listed in Table 10.

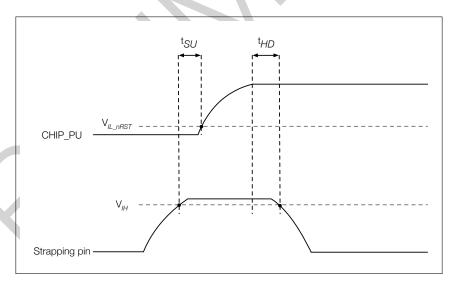


Figure 6: Setup and Hold Times for the Strapping Pin

Table 10: Parameter Descriptions of Setup and Hold Times for the Strapping Pin

Parameter	Description	
t_{SU}	Setup time before CHIP_PU goes from low to high	0
t_{HD}	Hold time after CHIP_PU goes high	3

3. Functional Description

3.1 CPU and Memory

3.1.1 CPU

ESP32-S3 has a low-power Xtensa® dual-core 32-bit LX7 microprocessor with the following features:

- Five-stage pipeline that supports the clock frequency of up to 240 MHz
- 16-bit/24-bit instruction set providing high code density
- 32-bit customized instruction set and 128-bit data bus that provide high computing performance
- Support for single-precision floating-point unit (FPU)
- 32-bit multiplier and 32-bit divider
- Unbuffered GPIO instructions
- 32 interrupts at six levels
- Windowed ABI with 64 physical general registers
- Trace function with TRAX compressor, up to 16 KB trace memory
- JTAG for debugging

3.1.2 Internal Memory

ESP32-S3's internal memory includes:

- 384 KB ROM: for booting and core functions
- 512 KB on-chip SRAM: for data and instructions, running at a configurable frequency of up to 240 MHz
- RTC FAST memory: 8 KB SRAM that supports read/write/instruction fetch by the main CPU (LX7 dual-core processor). It can retain data in Deep-sleep mode.
- RTC SLOW Memory: 8 KB SRAM that supports read/write/instruction fetch by the main CPU (LX7 dual-core processor) or coprocessors. It can retain data in Deep-sleep mode.
- 4 kbit eFuse: 1652 bits are reserved for user data, such as encryption key and device ID.
- SiP flash and PSRAM: See details in Table 1 Comparison.

3.1.3 External Flash and RAM

ESP32-S3 supports SPI, Dual SPI, Quad SPI, Octal SPI, QPI and OPI interfaces that allow connection to multiple external flash and RAM.

The external flash and RAM can be mapped into the CPU instruction memory space and read-only data memory space. The external RAM can also be mapped into the CPU data memory space. ESP32-S3 supports up to 1 GB of external flash and RAM, and hardware encryption/decryption based on XTS-AES to protect users' programs and data in flash and external RAM.

Through high-speed caches, ESP32-S3 can support at a time up to:

- External flash or RAM mapped into 32 MB instruction space as individual blocks of 64 KB
- External RAM mapped into 32 MB data space as individual blocks of 64 KB. 8-bit, 16-bit, 32-bit, and 128-bit reads and writes are supported. External flash can also be mapped into 32 MB data space as individual blocks of 64 KB, but only supporting 8-bit, 16-bit, 32-bit and 128-bit reads.

Note:

After ESP32-S3 is initialized, firmware can customize the mapping of external RAM or flash into the CPU address space.

3.1.4 Address Mapping Structure

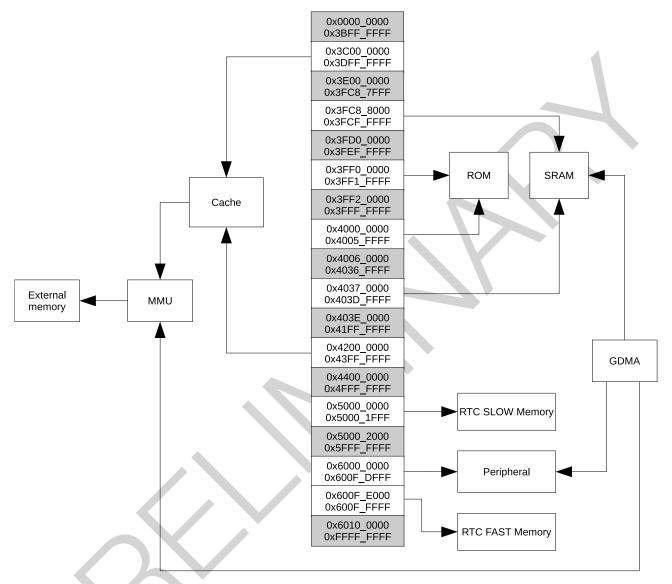


Figure 7: Address Mapping Structure

Note:

The memory space with gray background is not available to users.

3.1.5 Cache

ESP32-S3 has an instruction cache and a data cache shared by the two CPU cores. Each cache can be partitioned into multiple banks and has the following features:

- Instruction cache: 16 KB (one bank) or 32 KB (two banks)
 Data cache: 32 KB (one bank) or 64 KB (two banks)
- Instruction cache: four-way or eight-way set associative

Data cache: four-way set associative

- Block size of 16 bytes or 32 bytes for both instruction cache and data cache
- Pre-load function
- Lock function
- · Critical word first and early restart

3.2 System Clocks

3.2.1 CPU Clock

The CPU clock has three possible sources:

- External main crystal clock
- Internal fast RC oscillator (typically about 17.5 MHz, and adjustable)
- PLL clock

The application can select the clock source from the three clocks above. The selected clock source drives the CPU clock directly, or after division, depending on the application. Once the CPU is reset, the default clock source would be the external main crystal clock divided by 2.

3.2.2 RTC Clock

The RTC slow clock is used for RTC counter, RTC watchdog and low-power controller. It has three possible sources:

- External low-speed (32 kHz) crystal clock
- Internal slow RC oscillator (typically about 136 kHz, and adjustable)
- Internal fast RC oscillator divided clock (derived from the internal fast RC oscillator divided by 256)

The RTC fast clock is used for RTC peripherals and sensor controllers. It has two possible sources:

- External main crystal clock divided by 2
- Internal fast RC oscillator (typically about 17.5 MHz, and adjustable)

3.3 Analog Peripherals

3.3.1 Analog-to-Digital Converter (ADC)

ESP32-S3 integrates two 12-bit SAR ADCs and supports measurements on 20 channels (analog-enabled pins). For power-saving purpose, the ULP coprocessors in ESP32-S3 can also be used to measure voltage in sleep modes. By using threshold settings or other methods, we can awaken the CPU from sleep modes.

3.3.2 Temperature Sensor

The temperature sensor generates a voltage that varies with temperature. The voltage is internally converted via an ADC into a digital value.

The temperature sensor has a range of –20 °C to 110 °C. It is designed primarily to sense the temperature changes inside the chip. The temperature value depends on factors such as microcontroller clock frequency or I/O load. Generally, the chip's internal temperature is higher than the ambient temperature.

3.3.3 Touch Sensor

ESP32-S3 has 14 capacitive-sensing GPIOs, which detect variations induced by touching or approaching the GPIOs with a finger or other objects. The low-noise nature of the design and the high sensitivity of the circuit allow relatively small pads to be used. Arrays of pads can also be used, so that a larger area or more points can be detected. The touch sensing performance can be further enhanced by the waterproof design and digital filtering feature.

3.4 Digital Peripherals

3.4.1 General Purpose Input / Output Interface (GPIO)

ESP32-S3 has 45 GPIO pins which can be assigned various functions by configuring corresponding registers. Besides digital signals, some GPIOs can be also used for analog functions, such as ADC, touch sensing, etc.

All GPIOs have selectable internal weak pull-up or pull-down, or can be set to high impedance. When these GPIOs are configured as an input, the input value can be read by software through the register. Input GPIOs can also be set to generate edge-triggered or level-triggered CPU interrupts. All digital IO pins are bi-directional, non-inverting, and tristate, including input and output buffers with tristate control. These pins can be multiplexed with other functions, such as UART, SPI, etc. For low-power operations, the GPIOs can be set to holding state.

The IO MUX and the GPIO matrix are used to route signals from peripherals to GPIO pads. Together they provide highly configurable I/O. Using GPIO Matrix, peripheral input signals can be configured from any IO pads while peripheral output signals can be configured to any IO pad. For more information about IO MUX and GPIO matrix, please refer to ESP32-S3 Technical Reference Manual.

3.4.2 Serial Peripheral Interface (SPI)

ESP32-S3 features four SPI interfaces (SPI0, SPI1, SPI2 and SPI3). SPI0 and SPI1 can be configured to operate in SPI memory mode; SPI2 and SPI3 can be configured to operate in general-purpose SPI mode.

SPI Memory mode

In SPI memory mode, SPI0 and SPI1 interface with external SPI memory. Data transmission is in multiples of bytes. Up to 8-line SDR/DDR (Single Data Rate/Double Data Rate) reads and writes are supported. The clock frequency is configurable to a maximum of 120 MHz for OPI SDR/DDR mode.

SPI2 General-purpose SPI (GP-SPI) mode

SPI2 can operate in master and slave modes. The master mode supports two-line full-duplex communication and single-/two-/four-/eight-line half-duplex communication. The slave mode supports two-line full-duplex communication and single-/two-/four-line half-duplex communication. The host's clock frequency is configurable. Data transmission is in multiples of bytes. The clock polarity (CPOL) and phase (CPHA) are also configurable. The SPI2 interface supports DMA.

- In two-line full-duplex communication mode, the host's clock frequency is configurable to 80 MHz at most, and the slave's clock frequency to 60 MHz at most. Four modes of SPI transfer format are supported. Only SDR reads and writes are supported.
- In single-/two-/four-/eight-line half-duplex communication mode, the host's clock frequency is configurable to 80 MHz at most for SDR reads/writes and 40 MHz for DDR reads/writes. Four modes of SPI transfer format are supported.

 In single-/two-/four-line half-duplex communication mode, the slave's clock frequency is configurable to 60 MHz at most. Only SDR reads and writes are supported. Four modes of SPI transfer format are supported.

• SPI3 General-purpose SPI (GP-SPI) mode

SPI3 can operate in master and slave modes, in two-line full-duplex and single-line, two-line and four-line half-duplex communication modes. Only SDR reads and writes are supported. The host's clock frequency is configurable. Data transmission is in multiples of bytes. The clock polarity (CPOL) and phase (CPHA) are also configurable. The SPI3 interface supports DMA.

- In two-line full-duplex communication mode, the host's clock frequency is configurable to a maximum of 80 MHz, and the slave's clock frequency to a maximum of 60 MHz. Four modes of SPI transfer format are supported.
- In single-line, two-line and four-line half-duplex communication mode, the host's clock frequency is configurable to a maximum of 80 MHz, and the slave's clock frequency to 60 MHz at most. Four modes of SPI transfer format are supported.

In most cases, the data port connection between ESP32-S3 and external flash is as follows:

External Flash Data Port Chip Pin **SPI Single-Line Mode SPI Two-Line Mode SPI Four-Line Mode SPI Eight-Line Mode** SPID (SPID) DI 100 100 100 SPIQ (SPIQ) DO 101 IO1 IO1 SPIWP (SPIWP) WP# 102 102 SPIHD (SPIHD) HOLD# 103 103 GPIO33 104 GPIO34 105 GPIO35 106 GPIO36 107 GPIO37 DQS

Table 11: Connection Between ESP32-S3 and External Flash

3.4.3 LCD Interface

ESP32-S3 supports 8-bit ~16-bit parallel RGB, I8080, and MOTO6800 interfaces. These interfaces operate at 40 MHz or lower, and support conversion among RGB565, YUV422, YUV420, and YUV411.

3.4.4 Camera Interface

ESP32-S3 supports an 8-bit ~16-bit DVP image sensor, with clock frequency of up to 40 MHz. The camera interface supports conversion among RGB565, YUV422, YUV420, and YUV411.

3.4.5 Universal Asynchronous Receiver Transmitter (UART)

ESP32-S3 has three UART interfaces, i.e., UART0, UART1, and UART2, which support IrDA and asynchronous communication (RS232 and RS485) at a speed of up to 5 Mbps. The UART controller provides hardware management of the CTS and RTS signals and software flow control (XON and XOFF). All of the interfaces can be accessed by the DMA controller or directly by the CPU.

3.4.6 I2C Interface

ESP32-S3 has two I2C bus interfaces which are used for I2C master mode or slave mode, depending on the user's configuration. The I2C interfaces support:

- Standard mode (100 kbit/s)
- Fast mode (400 kbit/s)
- Up to 800 kbit/s (constrained by SCL and SDA pull-up strength)
- 7-bit and 10-bit addressing mode
- Double addressing mode (slave addressing and slave register addressing)

The hardware provides a command abstraction layer to simplify the usage of the I2C peripheral

3.4.7 I2S Interface

ESP32-S3 includes two standard I2S interfaces. They can operate in master mode or slave mode, in full-duplex mode or half-duplex communication mode, and can be configured to operate with an 8-bit, 16-bit, 24-bit, or 32-bit resolution as an input or output channel. BCK clock frequency, from 10 kHz up to 40 MHz, is supported.

The I2S interface has a dedicated DMA controller. It supports TDM PCM, TDM MSB alignment, TDM LSB alignment, TDM Phillips, and PDM interface.

3.4.8 Remote Control Peripheral

The Remote Control Peripheral (RMT) supports four channels of infrared remote transmission and four channels of infrared remote reception. By controlling pulse waveform through software, it supports various infrared and other single wire protocols. All eight channels share a 384×32 -bit memory block to store transmit or receive waveforms.

3.4.9 Pulse Counter

The pulse counter captures pulse and counts pulse edges through multiple modes. It has four channels, each of which captures four signals at a time. The four input signals include two pulse signals and two control signals.

3.4.10 LED PWM Controller

The LED PWM controller can generate independent digital waveforms on eight channels. The LED PWM controller:

- Can generate a digital waveform with configurable periods and duty cycle. The duty cycle resolution can be up to 14 bits within a 1 ms period.
- Has multiple clock sources, including APB clock and external main crystal clock.
- Can operate when the CPU is in Light-sleep mode.
- Supports gradual increase or decrease of duty cycle, which is useful for the LED RGB color-fading generator.

3.4.11 USB 1.1 OTG

ESP32-S3 features a full-speed USB OTG interface along with an integrated transceiver. The USB OTG interface complies with the USB 1.1 specification. It has the following features:

- Software-configurable endpoint settings and suspend/resume
- Dynamic FIFO size
- Session request protocol (SRP) and host negotiation protocol (HNP)
- · Supports the full-speed USB PHY integrated in the chip or external USB PHY (but cannot use the same USB PHY together with the USB Serial/JTAG controller)

3.4.12 USB Serial/JTAG Controller

ESP32-S3 integrates a USB Serial/JTAG controller that:

- Complies with the full-speed USB 2.0 specification, with data rate up to 12 Mbit/s (Note that high-speed mode at 480 Mbit/s is not supported)
- Contains CDC-ACM virtual serial port and JTAG adapter functionality
- Supports programming SiP flash and external flash
- Supports CPU debugging with compact JTAG instructions
- Supports the full-speed USB PHY integrated in the chip or external USB PHY (but cannot use the same USB PHY together with USB 1.1 OTG)

3.4.13 Motor Control PWM (MCPWM)

ESP32-S3 integrates two MCPWM that can be used to drive digital motors and smart light. This controller includes PWM timers, PWM operators, and a dedicated capture submodule. PWM timers can be synchronized or work independently. Each PWM operator generates a waveform for one PWM channel. The dedicated capture submodule can accurately capture external timing events.

3.4.14 SD/MMC Host Controller

ESP32-S3 has an SD/MMC Host Controller with the following features:

- Secure Digital (SD) memory version 3.0 and version 3.01
- Secure Digital I/O (SDIO) version 3.0
- Consumer Electronics Advanced Transport Architecture (CE-ATA) version 1.1
- Multimedia Cards (MMC version 4.41, eMMC version 4.5 and version 4.51)

The controller allows up to 80 MHz clock output in 1-bit, 4-bit or 8-bit data bus mode. In 4-bit mode, ESP32-S3 supports two SD/SDIO/MMC 4.41 cards, and one SD card operating at 1.8 V.

3.4.15 GDMA Controller

ESP32-S3 has a general-purpose DMA controller (GDMA) with five independent channels for transmitting and another five independent channels for receiving. These ten channels are shared by peripherals that have DMA feature, and support dynamic priority.

The DMA controller controls data transfer using linked lists. It allows peripheral-to-memory and memory-to-memory data transfer at a high speed. All channels can access internal and external RAM.

The ten peripherals on ESP32-S3 with DMA feature are SPI2, SPI3, UHCI0, I2S0, I2S1, LCD/CAM, AES, SHA, ADC, and RMT.

3.4.16 TWAI® Controller

ESP32-S3 has a TWAI® controller with the following features:

- Compatible with ISO 11898-1 protocol (CAN Specification 2.0)
- Standard frame format (11-bit ID) and extended frame format (29-bit ID)
- Bit rates from 1 Kbit/s to 1 Mbit/s
- Multiple modes of operation: Normal, Listen Only, and Self-Test (no acknowledgment required)
- 64-byte receive FIFO
- Acceptance filter (single and dual filter modes)
- Error detection and handling: error counters, configurable error interrupt threshold, error code capture, arbitration lost capture

3.5 Radio and Wi-Fi

The ESP32-S3 radio consists of the following blocks:

- 2.4 GHz receiver
- 2.4 GHz transmitter
- Bias and regulators
- Balun and transmit-receive switch
- · Clock generator

3.5.1 2.4 GHz Receiver

The 2.4 GHz receiver demodulates the 2.4 GHz RF signal to quadrature baseband signals and converts them to the digital domain with two high-resolution, high-speed ADCs. To adapt to varying signal channel conditions, ESP32-S3 integrates RF filters, Automatic Gain Control (AGC), DC offset cancelation circuits, and baseband filters.

3.5.2 2.4 GHz Transmitter

The 2.4 GHz transmitter modulates the quadrature baseband signals to the 2.4 GHz RF signal, and drives the antenna with a high-powered CMOS power amplifier. The use of digital calibration further improves the linearity of the power amplifier.

To compensate for receiver imperfections, additional calibration methods are built into the chip, including:

- Carrier leakage compensation
- I/Q amplitude/phase matching
- Baseband nonlinearities suppression
- RF nonlinearities suppression
- Antenna matching

These built-in calibration routines reduce the cost and time to the market for your product, and eliminate the need for specialized testing equipment.

3.5.3 Clock Generator

The clock generator produces quadrature clock signals of 2.4 GHz for both the receiver and the transmitter. All components of the clock generator are integrated into the chip, including inductors, varactors, filters, regulators, and dividers.

The clock generator has built-in calibration and self-test circuits. Quadrature clock phases and phase noise are optimized on chip with patented calibration algorithms which ensure the best performance of the receiver and the transmitter.

3.5.4 Wi-Fi Radio and Baseband

The ESP32-S3 Wi-Fi radio and baseband support the following features:

- 802.11b/g/n
- 802.11n MCS0-7 that supports 20 MHz and 40 MHz bandwidth
- 802.11n MCS32
- 802.11n 0.4 μs guard-interval
- Data rate up to 150 Mbps
- RX STBC (single spatial stream)
- Adjustable transmitting power
- Antenna diversity;
 ESP32-S3 supports antenna diversity with an external RF switch. This switch is controlled by one or more GPIOs, and used to select the best antenna to minimize the effects of channel imperfections.

3.5.5 Wi-Fi MAC

ESP32-S3 implements the full 802.11 b/g/n Wi-Fi MAC protocol. It supports the Basic Service Set (BSS) STA and SoftAP operations under the Distributed Control Function (DCF). Power management is handled automatically with minimal host interaction to minimize the active duty period.

The ESP32-S3 Wi-Fi MAC applies the following low-level protocol functions automatically:

- 4 × virtual Wi-Fi interfaces
- Simultaneous Infrastructure BSS Station mode, SoftAP mode, and Station + SoftAP mode
- RTS protection, CTS protection, Immediate Block ACK
- Fragmentation and defragmentation
- TX/RX A-MPDU, TX/RX A-MSDU
- TXOP
- WMM
- GCMP, CCMP, TKIP, WAPI, WEP, and BIP
- Automatic beacon monitoring (hardware TSF)
- 802.11mc FTM

3.5.6 Networking Features

Users are provided with libraries for TCP/IP networking, ESP-WIFI-MESH networking, and other networking protocols over Wi-Fi. TLS 1.2 support is also provided.

3.6 Bluetooth LE

ESP32-S3 includes a Bluetooth Low Energy subsystem that integrates a hardware link layer controller, an RF/modem block and a feature-rich software protocol stack. It supports the core features of Bluetooth 5 and Bluetooth mesh.

3.6.1 Bluetooth LE Radio and PHY

Bluetooth Low Energy radio and PHY in ESP32-S3 support:

- 1 Mbps PHY
- 2 Mbps PHY for high transmission speed and high data throughput
- Coded PHY for high RX sensitivity and long range (125 Kbps and 500 Kbps)
- Class 1 transmit power without external PA
- Listen before talk (LBT), implemented in hardware
- Antenna diversity with an external RF switch. This switch is controlled by one or more GPIOs, and used to select the best antenna to minimize the effects of channel imperfections.

3.6.2 Bluetooth LE Link Layer Controller

Bluetooth Low Energy Link Layer Controller in ESP32-S3 supports:

- LE advertising extensions, to enhance broadcasting capacity and broadcast more intelligent data
- Multiple advertisement sets
- · Simultaneous advertising and scanning
- Multiple connections in simultaneous central and peripheral roles
- Adaptive frequency hopping and channel assessment
- LE channel selection algorithm #2
- Connection parameter update
- High duty cycle non-connectable advertising
- LE privacy 1.2
- LE data packet length extension
- Link layer extended scanner filter policies
- Low duty cycle directed advertising
- Link layer encryption
- LE Ping

3.7 RTC and Low-Power Management

3.7.1 Power Management Unit (PMU)

With the use of advanced power-management technologies, ESP32-S3 can switch between different power modes.

- Active mode: CPU and chip radio are powered on. The chip can receive, transmit, or listen.
- Modem-sleep mode: The CPU is operational and the clock speed can be reduced. The wireless baseband and radio are disabled, but wireless connection can remain active.
- Light-sleep mode: The CPU is paused. The RTC peripherals, as well as the ULP coprocessor can be woken up periodically by the timer. Any wake-up events (MAC, host, RTC timer, or external interrupts) will wake up the chip. Wireless connection can remain active. Users can optionally decide what peripherals to shut down/keep on (refer to Figure 1), for power-saving purpose.
- **Deep-sleep mode**: CPU and most peripherals are powered down. Only the RTC memory and RTC peripherals are powered on. Wi-Fi connection data are stored in the RTC memory. The ULP coprocessor is functional.
- **Hibernation mode**: The internal fast RC oscillator and ULP co-processor are disabled. Only one RTC timer on the slow clock is active. The RTC GPIO function is disabled and can only wake up the chip from the Hibernation mode. The RTC timer is also responsible for waking up the chip.

For power consumption in different power modes, please refer to Table 19.

3.7.2 Ultra-Low-Power Coprocessor

The ULP coprocessor is designed as a simplified, low-power replacement of CPU in sleep modes. It can be also used to supplement the functions of the CPU in normal working mode. The ULP coprocessor and RTC memory remain powered on during the Deep-sleep mode. Hence, the developer can store a program for the ULP coprocessor in the RTC slow memory to access RTC GPIO, RTC peripheral devices, RTC timers and internal sensors in Deep-sleep mode.

ESP32-S3 has two ULP coprocessors, one based on RISC-V instruction set architecture (ULP-RISC-V) and the other on finite state machine (ULP-FSM). The clock of the coprocessors is the internal fast RC oscillator.

ULP-RISC-V has the following features:

- Support for RV32IMC instruction set
- Thirty-two 32-bit general-purpose registers
- 32-bit multiplier and divider
- Support for interrupts
- Booted by the CPU, its dedicated timer, or RTC GPIO

ULP-FSM has the following features:

- Support for common instructions including arithmetic, jump, and program control instructions
- Support for on-board sensor measurement instructions
- Booted by the CPU, its dedicated timer, or RTC GPIO

Note that these two coprocessors cannot work simultaneously.

3.8 Timers and Watchdogs

3.8.1 General Purpose Timers

ESP32-S3 is embedded with four 54-bit general-purpose timers, which are based on 16-bit prescalers and 54-bit auto-reload-capable up/down-timers.

The timers' features are summarized as follows:

- A 16-bit clock prescaler, from 2 to 65536
- A 54-bit time-base counter programmable to be incrementing or decrementing
- Able to read real-time value of the time-base counter
- · Halting and resuming the time-base counter
- Programmable alarm generation
- Timer value reload (Auto-reload at alarm or software-controlled instant reload)
- Level interrupt generation

3.8.2 System Timer

ESP32-S3 integrates a 52-bit system timer, which has two 52-bit counters and three comparators. The system timer has the following features:

- Counters with a clock frequency of 16 MHz
- Three types of independent interrupts generated according to alarm value
- Two alarm modes: target mode and period mode
- 52-bit target alarm value and 26-bit periodic alarm value
- Read sleep time from RTC timer when the chip is awaken from Deep-sleep or Light-sleep mode
- Counters can be stalled if the CPU is stalled or in OCD mode

3.8.3 Watchdog Timers

The ESP32-S3 contains three watchdog timers: one in each of the two timer groups (called Main System Watchdog Timers, or MWDT) and one in the RTC Module (called the RTC Watchdog Timer, or RWDT).

During the flash boot process, RWDT and the first MWDT are enabled automatically in order to detect and recover from booting errors.

Watchdog timers have the following features:

- Four stages, each with a programmable timeout value. Each stage can be configured, enabled and disabled separately
- Interrupt, CPU reset, or core reset for MWDT upon expiry of each stage; interrupt, CPU reset, core reset, or system reset for RWDT upon expiry of each stage
- 32-bit expiry counter
- Write protection, to prevent RWDT and MWDT configuration from being altered inadvertently
- Flash boot protection
 If the boot process from an SPI flash does not complete within a predetermined period of time, the watchdog will reboot the entire main system.

3.9 Cryptographic Hardware Accelerators

ESP32-S3 is equipped with hardware accelerators of general algorithms, such as AES (FIPS PUB 197), ECB/CBC/OFB/CFB/CTR (NIST SP 800-38A), SHA (FIPS PUB 180-4), RSA, and ECC. The chip also supports independent arithmetic, such as Big Integer Multiplication and Big Integer Modular Multiplication. The maximum operation length for RSA and Big Integer Modular Multiplication is 4096 bits. The maximum factor length for Big Integer Multiplication is 2048 bits.

Physical Security Features 3.10

- Transparent external flash and RAM encryption (AES-XTS) with software inaccessible key prevents unauthorized readout of user application code or data.
- Secure Boot feature uses a hardware root of trust to ensure only signed firmware (with RSA-PSS signature) can be booted.
- HMAC module uses a software inaccessible MAC key to generate MAC signatures for identity verification, as well as other uses.
- Digital Signature module uses a software inaccessible secure key to generate RSA signatures for identity
- · World controller provides two running environment for software. All hardware and software resources are sorted to two groups, and placed in either secure or general world. The secure world cannot be accessed by hardware in the general world, thus establishing a security boundary.

Peripheral Pin Configurations 3.11

Table 12: Peripheral Pin Configurations

Interface	Signal	Pin	Function
	ADC1_CH0	GPIO1	
	ADC1_CH1	GPIO2	
	ADC1_CH2	GPIO3	
	ADC1_CH3	GPIO4	
	ADC1_CH4	GPIO5	
	ADC1_CH5	GPIO6	
	ADC1_CH6	GPI07	
	ADC1_CH7	GPIO8	
	ADC1_CH8	GPIO9	
ADC	ADC1_CH9	GPIO10	Two 12-bit SAR ADCs
ADO	ADC2_CH0	GPIO11	TWO 12-BIT SALLADOS
	ADC2_CH1	GPIO12	
	ADC2_CH2	GPIO13	
	ADC2_CH3	GPIO14	
	ADC2_CH4	XTAL_32K_P	
	ADC2_CH5	XTAL_32K_N	
	ADC2_CH6	GPIO17	
	ADC2_CH7	GPIO18	
	ADC2_CH8	GPIO19	

Interface	Signal	Pin	Function
	ADC2_CH9	GPIO20	
	TOUCH1	GPIO1	
	TOUCH2	GPIO2	
	TOUCH3	GPIO3	
	TOUCH4	GPIO4	
	TOUCH5	GPIO5	
	TOUCH6	GPIO6	
Tb	TOUCH7	GPIO7	
Touch sensor	TOUCH8	GPIO8	Capacitive touch sensors
	TOUCH9	GPIO9	
	TOUCH10	GPIO10	
	TOUCH11	GPIO11	
	TOUCH12	GPIO12	
	TOUCH13	GPIO13	
	TOUCH14	GPIO14	
	MTDI	MTDI	
I-10	MTCK	MTCK	1
JTAG	MTMS	MTMS	JTAG for software debugging
	MTDO	MTDO	
	U0RXD_in		
	U0CTS_in		
	U0DSR_in		
	U0TXD_out		
	U0RTS_out		
	U0DTR_out		
	U1RXD_in		
	U1CTS_in		
LIADT	U1DSR_in	A OPIO	Three UART devices with
UART	U1TXD_out	Any GPIO pins	hardware flow-control and DMA
	U1RTS_out		
	U1DTR_out		
	U2RXD_in		
	U2CTS_in		
	U2DSR_in		
	U2TXD_out		
	U2RTS_out		
	U2DTR_out		
	I2CEXT0_SCL_in/_out		
100	I2CEXT0_SDA_in/_out	A ODIO	Two I2C devices in slave or
I2C	I2CEXT1_SCL_in/_out	Any GPIO pins	master mode
	I2CEXT1_SDA_in/_out		
LED PWM	LEDC_LS_SIG_out0~7	Any GPIO pins	Eight independent channels.

Interface	Signal	Pin	Function
	I2S00_BCK_in		
	I2S0_MCLK_in		
	12S0O_WS_in		
	I2S0I_SD_in		
	I2S0I_SD1_in		
	12S0I_SD2_in		
	12S0I_SD3_in		
	I2S0I_BCK_in		
	I2S0I_WS_in		
	I2S1O_BCK_in		
	I2S1_MCLK_in		
	I2S1O_WS_in		
	I2S1I_SD_in		
100	I2S1I_BCK_in	A ODIO	Stereo input and output from/to
I2S	I2S1I_WS_in	Any GPIO pins	the audio codec
	I2S0O_BCK_out		
	I2S0_MCLK_out		
	12S0O_WS_out		
	12S0O_SD_out		
	12S0O_SD1_out		
	I2S0I_BCK_out		
	I2S0I_WS_out		
	I2S1O_BCK_out		
	I2S1_MCLK_out		
	I2S1O_WS_out		
	I2S1O_SD_out		
	I2S1I_BCK_out		
	I2S1I_WS_out		
	LCD_PCLK		
	LCD_DC		
	LCD_V_SYNC		
	LCD_H_SYNC		
	LCD_H_ENABLE		
	LCD_DATA_out0~15		8 ~16 data transmission to LCD
LCD_CAMERA	LCD_CS	Any GPIO pins	interface and 8 ~16 data
	CAM_CLK		reception by camera interface
	CAM_V_SYNC		
	CAM_H_SYNC		
	CAM_H_ENABLE		
	CAM_PCLK		
	CAM_DATA_in0~15		
Remote Control	RMT_SIG_in0~3	Any CDIC sins	Four channels for an IR
Peripheral	RMT_SIG_out0~3	Any GPIO pins	transceiver of various wave forms

Interface	Signal	Pin	Function		
	SPICLK_out_mux	SPICLK			
	SPICS0_out	SPICS0			
	SPICS1_out	SPICS1			
SPI0/1	SPID_in/_out	SPID			
	SPIQ_in/_out	SPIQ	Support Standard SPI, Dual SPI,		
	SPIWP_in/_out	SPIWP	QSPI, QPI, OSPI, and OPI that		
01 107 1	SPIHD_in/_out	SPIHD	allow connection to external flash		
	SPID4_in/_out	GPIO33	and RAM.		
	SPID5_in/_out	GPIO34			
	SPID6_in/_out	GPIO35			
	SPID7_in/_out	GPIO36			
	SPIDQS_in/_out	GPIO37			
	FSPICLK_in/_out_mux		Support: • master mode of SPI, Dual		
	FSPICS0_in/_out		SPI, Quad SPI,Octal SPI, QPI, and OPI, and slave		
	FSPICS1~5_out		mode of SPI, Dual SPI,		
	FSPID_in/_out	Any GPIO pins	Quad SPI, and QPI; • connection to external		
SPI2	FSPIQ_in/_out		flash, RAM, and other SPI devices;		
	FSPIWP_in/_out		four modes of SPI transfer		
	FSPIHD_in/_out		format; • configurable SPI		
	FSPIIO4~7_in/_out		frequency; • 64-byte FIFO or DMA		
	FSPIDQS_out		buffer.		
	SPI3_CLK_in/_out_mux		Support:		
	SPI3_CS0_in/_out		 master and slave modes of 		
	SPI3_CS1_out		SPI, Dual SPI, Quad SPI,		
	SPI3_CS2_out		and QPI;		
SPI3	SPI3_D_in/_out	Any GPIO pins	• four modes of SPI transfer		
	SPI3_Q_in/_out	_	format; • configurable frequency;		
	SPI3_WP_in/_out		64-byte FIFO or DMA		
	SPI3_HD_in/_out		buffer.		
	PCNT_SIG_CH0_in0~3				
	PCNT_SIG_CH1_in0~3		Capture pulse and count pulse		
Pulse counter	PCNT_CTRL_CH0_in0~3	Any GPIO pins	edges in seven modes		
	PCNT_CTRL_CH1_in0~3				

Interface	Signal	Pin	Function
	D-	GPIO19 (for internal PHY)	
	D+	GPIO20 (for internal PHY)	
	VP	MTMS (for external PHY)	
LICE OTO	VM	MTDI (for external PHY)	Full-speed USB OTG (USB OTG
USB OTG	RCV	GPIO21 (for external PHY)	supports both high-speed
	OEN	MTDO (for external PHY)	on-chip PHY and external PHY)
	VPO	MTCK (for external PHY)	
	VMO	GPIO38 (for external PHY)	
	D-	GPIO19 (for internal PHY)	
	D+	GPIO20 (for internal PHY)	Flash programming and CPU
USB	VP	MTMS (for external PHY)	debugging (USB Serial/JTAG
Serial/JTAG	VM	MTDI (for external PHY)	controller supports both
controller	OEN	MTDO (for external PHY)	high-speed on-chip PHY and
	VPO	MTCK (for external PHY)	external PHY)
	VMO	GPIO38 (for external PHY)	
	SDHOST_CCLK_out_1~2		
	SDHOST_RST_N_1~2		
	SD-		
	HOST_CCMD_OD_PULLUP_EN_N	4 /	
	SDIO_TOHOST_INT_out		
	SDHOST_CCMD_in/_out_1		
	SDHOST_CCMD_in/_out_2		
	SDHOST_CDATA_in/_out_10		
	SDHOST_CDATA_in/_out_11		
	SDHOST_CDATA_in/_out_12		
	SDHOST_CDATA_in/_out_13		
	SDHOST_CDATA_in/_out_14		
SD/MMC	SDHOST_CDATA_in/_out_15	Any GPIO pins	Secure Digital (SD) memory
Host Controller	SDHOST_CDATA_in/_out_16	7 try on to pine	version version 3.01 supported
	SDHOST_CDATA_in/_out_17		
	SDHOST_CDATA_in/_out_20		
	SDHOST_CDATA_in/_out_21		
	SDHOST_CDATA_in/_out_22		
	SDHOST_CDATA_in/_out_23		
	SDHOST_CDATA_in/_out_24		
	SDHOST_CDATA_in/_out_25		
	SDHOST_CDATA_in/_out_26		
	SDHOST_CDATA_in/_out_27		
	SDHOST_DATA_STROBE_1~2		
	SDHOST_CARD_DETECT_N_1~2		
	SD-		
	HOST_CARD_WRITE_PRT_1~2		
	SDHOST_CARD_INT_N_1~2		

Interface	Signal	Pin	Function
	PWM0_SYNC0~2_in		
	PWM0_F0~2_in		
	PWM0_CAP0~2_in		
	PWM1_SYNC0~2_in		
	PWM1_F0~2_in		
	PWM1_CAP0~2_in		Two MCPWM input and output
	PWM0_out0a		pins. Signals include PWM
	PWM0_out0b		differential output signals, fault
MCPWM	PWM0_out1a	Any GPIO pins	input signals to be detected,
WO WW	PWM0_out1b	Any on 10 pins	input signals to be captured, and
	PWM0_out2a		external clock synchronization
	PWM0_out2b		signals
	PWM1_out0a		Signals
	PWM1_out0b		
	PWM1_out1a		
	PWM1_out1b		
	PWM1_out2a		
	PWM1_out2b		
	TWAI_RX		Compatible with ISO 11898-1
TWAI®	TWAI_TX	Any GPIO pins	protocol (CAN Specification 2.0).
Controller	TWAI_BUS_OFF_ON	711y di 10 pillo	Data rate up to 1 Mbit/s
	TWAI_CLKOUT		Data rate up to 1 Mibil/5

Electrical Characteristics

The values presented in this section are preliminary and may change with the final release of this datasheet.

4.1 **Absolute Maximum Ratings**

Stresses beyond the absolute maximum ratings listed in the table below may cause permanent damage to the device. These are stress ratings only, and do not refer to the functional operation of the device.

Table 13: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDDA, VDD3P3, VDD3P3_RTC,	Voltage applied to power supply pins -0.3		3.6	\/
VDD3P3_CPU, VDD_SPI	per power domain	-0.3	3.0	V
l _{output} *	Cumulative IO output current	7	1500	mA
T_{STORE}	Storage temperature	-40	150	°C

^{*} The chip worked properly after a 24-hour test in ambient temperature at 25 °C, and the IOs in three domains (VDD3P3_RTC, VDD3P3_CPU, VDD_SPI) output high logic level to ground.

Recommended Operating Conditions

Table 14: Recommended Operating Conditions

Symbol	Parameter		Min	Тур	Max	Unit
VDDA, VDD3P3	Voltage applied to power supply		3.0	3.3	3.6	V
VDD3P3_RTC	pins per pow	er domain				-
VDD_SPI (working as			1.8	3.3	3.6	V
input power supply) 1			1.0	5.5	5.0	V
VDD3P3_CPU ²	Voltage applied to power supply pin		3.0	3.3	3.6	V
I_{VDD} 3	Current delive	ered by external power supply	0.5		_	Α
		ESP32-S3			105	
	Ambient	ESP32-S3FN8		40 —	85	
T_A		ESP32-S3R2	-40		85	°C
	temperature	ESP32-S3R8			85	
		ESP32-S3R8V			85	

¹ For more information, please refer to Section 2.7 *Power Scheme*.

4.3 VDD_SPI Output Characteristics

² When VDD_SPI is used to drive peripherals, VDD3P3_CPU should comply with the peripherals' specifications. For more information, please refer to Table 15.

³ If you use a single power supply, the recommended output current is 500 mA or more.

Table 15: VDD_SPI Output Characteristics

Symbol	Parameter	Тур	Unit
R_{SPI}	On-resistance in 3.3 V mode	7.5	Ω
I_{SPI}	Output current in 1.8 V mode	40	mA

In real-life applications, when VDD_SPI works in 3.3 V output mode, VDD3P3_CPU may be affected by R_{SPI} . For example, when VDD3P3_CPU is used to drive a 3.3 V flash, it should comply with the following specifications:

VDD3P3_CPU > VDD_flash_min + I_flash_max* R_{SPI}

Among which, VDD_flash_min is the minimum operating voltage of the flash, and I_flash_max the maximum current.

For more information, please refer to section 2.7 Power Scheme.

4.4 DC Characteristics (3.3 V, 25 °C)

Table 16: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	_	2	_	рF
V_{IH}	High-level input voltage	$0.75 \times VDD^1$		VDD ¹ + 0.3	V
V_{IL}	Low-level input voltage	-0.3	_	$0.25 \times VDD^1$	V
$ I_{IH} $	High-level input current	-	_	50	nA
_{IL}	Low-level input current	_	_	50	nA
V_{OH}^2	High-level output voltage	$0.8 \times VDD^1$	_	_	V
V_{OL}^2	Low-level output voltage	_	_	$0.1 \times VDD^1$	V
1	High-level source current (VDD 1 = 3.3 V, V $_{OH}$		40		mA
$ _{OH}$	>= 2.64 V, PAD_DRIVER = 3)	_	40	_	ША
1.	Low-level sink current (VDD 1 = 3.3 V, V $_{OL}$ =		28		mA
$ \cdot _{OL}$	0.495 V, PAD_DRIVER = 3)	_	20	_	ША
R_{PU}	Internal weak pull-up resistor	_	45	_	kΩ
R_{PD}	Internal weak pull-down resistor	_	45	_	kΩ
\/	Chip reset release voltage (CHIP_PU voltage is	0.75 × VDD ¹		VDD ¹ + 0.3	V
V_{IH_nRST}	within the specified range)	0.75 x VDD	_	VDD + 0.3	V
V	Chip reset voltage (CHIP_PU voltage is within	-0.3		— 0.25 × VDD ¹	V
V_{IL_nRST}	the specified range)	_0.3		0.20 X VDD	V

¹ VDD is the I/O voltage for a particular power domain of pins.

4.5 ADC Characteristics

Table 17: ADC Characteristics

Symbol	Parameter	Min	Max	Unit
DNL (Differential nonlinearity) ¹	ADC connected to an external	1	1	LSB
DIVE (Differential Horifficearity)	100 nF capacitor; DC signal input;	-4	4	LOD

 $^{^2\,\}mathrm{V}_{OH}$ and V_{OL} are measured using high-impedance load.

Table 17 - cont'd from previous page

Symbol	Parameter	Min	Max	Unit
INL (Integral nonlinearity)	Ambient temperature at 25 °C;	-8	8	LSB
inc (integral normineanty)	Wi-Fi off	_0	O	LOD
Sampling rate	_	_	100	kSPS ²
Effective Range	ATTEN0	0	950	mV
	ATTEN1	0	1250	mV
	ATTEN2	0	1750	mV
	ATTEN3	0	3100	mV

¹ To get better DNL results, you can sample multiple times and apply a filter, or calculate the average value.

4.6 Current Consumption

The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 100% duty cycle.

Table 18: Wi-Fi Current Consumption Depending on RF Modes

Work Mode ¹	Descrip	Description		
Active (RF working)	TX	802.11b, 1 Mbps, @21 dBm	340	
		802.11g, 54 Mbps, @19 dBm	291	
		802.11n, HT20, MCS7, @18.5 dBm	283	
		802.11n, HT40, MCS7, @18.5 dBm	290	
	RX	802.11b/g/n, HT20	95	
		802.11n, HT40	97	

¹ The CPU work mode: Single core runs 32-bit data access instructions at 80 MHz, the other core is in idle state.

Note that data in Table 19 only applies to ESP32-S3, with no SiP flash or SiP PSRAM co-packaged inside.

Table 19: Current Consumption Depending on Work Modes (except Modem-sleep)

Work mode	Description	Тур	Unit
Light-sleep	_	240	μΑ
Deep-sleep	RTC memory and RTC peripherals are powered on.	8	μΑ
Hibernation	RTC memory is powered on. RTC peripherals are powered off.	7	μΑ
Power off	CHIP_PU is set to low level. The chip is powered off.	1	μΑ

² kSPS means kilo samples-per-second.

Table 20: Current Consumption in Modem-sleep Mode

	Frequency		Тур
Work mode	(MHz)	Description	(mA)
		WAITI (Dual core in idle state)	13.2
		Single core running 32-bit data access instructions, the other core in idle state	16.2
	40	Dual core running 32-bit data access instructions	18.7
		Single core running 128-bit data access instructions, the other core in idle state	19.9
		Dual core running 128-bit data access instructions	23.0
		WAITI	22.0
		Single core running 32-bit data access instructions, the other core in idle state	28.4
	80	Dual core running 32-bit data access instructions	33.1
		Single core running 128-bit data access instructions, the other core in idle state	35.1
NA la la		Dual core running 128-bit data access instructions	41.8
Modem-sleep		WAITI	27.6
		Single core running 32-bit data access instructions, the other core in idle state	39.9
	160	Dual core running 32-bit data access instructions	49.6
		Single core running 128-bit data access instructions, the other core in idle state	54.4
		Dual core running 128-bit data access instructions	66.7
		WAITI	32.9
		Single core running 32-bit data access instructions, the other core in idle state	51.2
	240	Dual core running 32-bit data access instructions	66.2
		Single core running 128-bit data access instructions, the other core in idle state	72.4
		Dual core running 128-bit data access instructions	91.7

4.7 Reliability

Table 21: Reliability Qualifications

Test Item	Test Conditions	Test Standard
ESD (Electro-Static	HBM (Human Body Mode) ¹ ± 2000 V	JESD22-A114
Discharge Sensitivity)	CDM (Charge Device Mode) ² ± 1000 V	JESD22-C101F
Latch up	Current trigger ± 200 mA	JESD78
Latorrup	Voltage trigger 1.5 \times VDD _{max}	JLSD/6

¹ JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.

 $^{^{2}}$ JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

4.8 Wi-Fi Radio

Table 22: Wi-Fi Frequency

Parameter	Min	Typ	Max
	(MHz)	(MHz)	(MHz)
Center frequency of operating channel	2412	_	2484

4.8.1 Wi-Fi RF Transmitter (TX) Specifications

Table 23: TX Power with Spectral Mask and EVM Meeting 802.11 Standards

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	21.0	
802.11b, 11 Mbps	_	21.0	_
802.11g, 6 Mbps	_	21.0	
802.11g, 54 Mbps	-	19.0	
802.11n, HT20, MSC0	_	20.0	
802.11n, HT20, MSC7		18.5	_
802.11n, HT40, MSC0	_	20.0	_
802.11n, HT40, MSC7	_	18.5	

Table 24: TX EVM Test

	Min	Тур	SL ¹
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps, @21 dBm	_	-24.5	-10
802.11b, 11 Mbps, @21 dBm	_	-24.5	-10
802.11g, 6 Mbps, @21 dBm	_	-21.5	- 5
802.11g, 54 Mbps, @19 dBm	_	-27.5	-25
802.11n, HT20, MSC0, @20 dBm		-22.0	-5
802.11n, HT20, MSC7, @18.5 dBm	_	-29.5	-27
802.11n, HT40, MSC0, @20 dBm		-22.0	-5
802.11n, HT40, MSC7, @18.5 dBm	_	-29.0	-27

¹ SL stands for standard limit value.

4.8.2 Wi-Fi RF Receiver (RX) Specifications

Table 25: RX Sensitivity

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	-98.4	_
802.11b, 2 Mbps		-95.4	_
802.11b, 5.5 Mbps		-93.0	_

Table 25 - cont'd from previous page

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 11 Mbps	_	-88.6	_
802.11g, 6 Mbps	_	-93.2	_
802.11g, 9 Mbps	_	-91.8	_
802.11g, 12 Mbps	_	-91.2	_
802.11g, 18 Mbps	_	-88.6	_
802.11g, 24 Mbps	_	-86.0	_
802.11g, 36 Mbps	_	-82.4	_
802.11g, 48 Mbps	_	-78.2	_
802.11g, 54 Mbps	_	-76.5	_
802.11n, HT20, MSC0	_	-92.6	
802.11n, HT20, MSC1	_	-91.0	
802.11n, HT20, MSC2	_	-88.2	_
802.11n, HT20, MSC3	_	-85.0	
802.11n, HT20, MSC4	-	-81.8	_
802.11n, HT20, MSC5	_	-77.4	_
802.11n, HT20, MSC6		-75.8	_
802.11n, HT20, MSC7	_	-74.2	_
802.11n, HT40, MSC0	1	-90.0	_
802.11n, HT40, MSC1	7	-88.0	
802.11n, HT40, MSC2	_	-85.2	_
802.11n, HT40, MSC3	_	-82.0	
802.11n, HT40, MSC4	_	-79.0	_
802.11n, HT40, MSC5	_	-74.4	
802.11n, HT40, MSC6	_	-72.8	
802.11n, HT40, MSC7	_	-71.4	

Table 26: Maximum RX Level

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	5	_
802.11b, 11 Mbps	_	5	_
802.11g, 6 Mbps	_	5	_
802.11g, 54 Mbps	_	0	_
802.11n, HT20, MSC0		5	_
802.11n, HT20, MSC7	_	0	_
802.11n, HT40, MSC0	_	5	_
802.11n, HT40, MSC7	_	0	_

Table 27: RX Adjacent Channel Rejection

	Min	Тур	Max
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps	_	35	_
802.11b, 11 Mbps	_	35	
802.11g, 6 Mbps		31	_
802.11g, 54 Mbps	_	20	
802.11n, HT20, MSC0	_	31	_
802.11n, HT20, MSC7		16	_
802.11n, HT40, MSC0	_	25	_
802.11n, HT40, MSC7	_	11	_

4.9 Bluetooth LE Radio

Table 28: Bluetooth LE Frequency

Parameter	Min	Typ	Max
	(MHz)	(MHz)	(MHz)
Center frequency of operating channel	2402		2480

Bluetooth LE RF Transmitter (TX) Specifications

Table 29: Transmitter Characteristics - Bluetooth LE 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-25.00	0	20.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB
	$ Max _{n=0, 1, 2,k}$	_	2.50	_	kHz
Carrier frequency offset and drift	$Max \left f_0 - f_n \right $	_	2.00	_	kHz
Carrier frequency offset and drift	$ Max f_{n-1} f_{n-5} $	_	1.39	_	kHz
	$ f_1 - f_0 $	_	0.80	_	kHz
	$\Delta f1_{avg}$	_	249.00	_	kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least		198.00		kHz
iviodulation characteristics	99.9% of all Δ $f2_{\text{max}}$)	_	190.00	_	KI IZ
	$\Delta f 2_{\rm avg}/\Delta f 1_{\rm avg}$	_	0.86	_	_
	±2 MHz offset	_	-37.00	_	dBm
In-band spurious emissions	±3 MHz offset	_	-42.00	_	dBm
	>±3 MHz offset	_	-44.00		dBm

Table 30: Transmitter Characteristics - Bluetooth LE 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-25.00	0	20.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB

Table 30 - cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
	$ \text{Max} _{n=0,1,2,k}$	_	2.50		kHz
Carrier frequency offset and drift	$ Max f_0 - f_n $		1.90	_	kHz
Carrier frequency offset and drift	$ \operatorname{Max} f_{n-1} f_{n-5} $		1.40	_	kHz
	$ f_1 - f_0 $	_	1.10	_	kHz
	$\Delta f1_{avg}$	_	499.00		kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least 99.9% of all Δ $f2_{\rm max}$)	_	416.00	-	kHz
	$\Delta f 2_{\rm avg}/\Delta f 1_{\rm avg}$	_	0.89	_	1 —
	±4 MHz offset	_	-43.80	1	dBm
In-band spurious emissions	±5 MHz offset	_	-45.80	_	dBm
	>±5 MHz offset	_	-47.00		dBm

Table 31: Transmitter Characteristics - Bluetooth LE 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-25.00	0	20.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB
			0.80	_	kHz
Carrier frequency offset and drift	$ Max f_0 - f_n $	_	0.98	_	kHz
Carrier frequency offset and drift	$ f_{n}-f_{n-3} $		0.30	_	kHz
	$ f_0 - f_3 $	_	1.00	_	kHz
	$\Delta f1_{avg}$	_	248.00	_	kHz
Modulation characteristics	Min $\Delta f1_{ ext{max}}$ (for at least	_	222.00	_	kHz
	99.9% of all $\Delta f1_{\text{max}}$				
	±2 MHz offset	_	-37.00	_	dBm
In-band spurious emissions	±3 MHz offset	_	-42.00	_	dBm
	>±3 MHz offset	_	-44.00		dBm

Table 32: Transmitter Characteristics - Bluetooth LE 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-25.00	0	20.00	dBm
ni transmit power	Gain control step	_	3.00		dB
		_	0.70		kHz
Carrier frequency offset and drift	$Max \left f_0 - f_n \right $	_	0.90		kHz
Carner frequency offset and drift	$ f_{n}-f_{n-3} $	_	0.85	_	kHz
	$ f_0 - f_3 $		0.34		kHz
	$\Delta f2_{ ext{avg}}$	_	213.00		kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least		196.00		kHz
	99.9% of all Δ $f2_{\text{max}}$)	_	190.00	_	NI 1Z
	±2 MHz offset		-37.00		dBm
In-band spurious emissions	±3 MHz offset	_	-42.00	_	dBm
	>±3 MHz offset	_	-44.00	_	dBm

4.9.2 Bluetooth LE RF Receiver (RX) Specifications

Table 33: Receiver Characteristics - Bluetooth LE 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-97.5	_	dBm
Maximum received signal @30.8% PER	_	_	8	_	dBm
Co-channel C/I	F = F0 MHz	_	9	_	dB
	F = F0 + 1 MHz	_	-3	_	dB
	F = F0 – 1 MHz	_	-3	_	dB
	F = F0 + 2 MHz	_	-28		dB
Adjacent channel selectivity C/I	F = F0 – 2 MHz	_	-30		dB
Adjacent channel selectivity C/1	F = F0 + 3 MHz		-31		dB
	F = F0 - 3 MHz		-33		dB
	F > F0 + 3 MHz		-32		dB
	F > F0 - 3 MHz		-36		dB
Image frequency	_		-32		dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	-	-39		dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	—	-31	_	dB
	30 MHz ~ 2000 MHz		-9		dBm
Out of hand blacking newformance	2003 MHz ~ 2399 MHz		-19	_	dBm
Out-of-band blocking performance	2484 MHz ~ 2997 MHz	_	-16	_	dBm
	3000 MHz ~ 12.75 GHz		-5		dBm
Intermodulation	_	_	-31	_	dBm

Table 34: Receiver Characteristics - Bluetooth LE 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER		_	-93.5	_	dBm
Maximum received signal @30.8% PER	_	_	3	_	dBm
Co-channel C/I	F = F0 MHz	_	10	_	dB
	F = F0 + 2 MHz	_	-8		dB
	F = F0 – 2 MHz	_	-5	_	dB
	F = F0 + 4 MHz		-31		dB
Adjacent channel selectivity C/I	F = F0 - 4 MHz		-33	_	dB
Adjacent charmer selectivity C/1	F = F0 + 6 MHz	_	-37		dB
	F = F0 - 6 MHz	_	-37	_	dB
	F > F0 + 6 MHz	_	-40		dB
	F > F0 - 6 MHz		-40	_	dB
Image frequency	_	_	-31		dB
Adjacent channel to image frequency	$F = F_{image} + 2 MHz$	_	-37	_	dB
Adjacent charmer to image frequency	$F = F_{image} - 2 \text{ MHz}$		-8	_	dB
	30 MHz ~ 2000 MHz	_	-16	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz	_	-20	_	dBm
Out-of-balld blocking performance	2484 MHz ~ 2997 MHz	_	-16	_	dBm

Table 34 - cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
	3000 MHz ~ 12.75 GHz	_	-16	_	dBm
Intermodulation	_	_	-30	_	dBm

Table 35: Receiver Characteristics - Bluetooth LE 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-104.5	_	dBm
Maximum received signal @30.8% PER	_	_	8		dBm
Co-channel C/I	F = F0 MHz	_	6		dB
	F = F0 + 1 MHz		-6	_	dB
	F = F0 – 1 MHz	_	- 5		dB
	F = F0 + 2 MHz	_	-32		dB
Adjacent channel selectivity C/I	F = F0 – 2 MHz	(-39	_	dB
Adjacent channel selectivity C/I	F = F0 + 3 MHz	_	-35	<u> </u>	dB
	F = F0 - 3 MHz	+	-45	_	dB
	F > F0 + 3 MHz	1	-35	_	dB
	F > F0 – 3 MHz	_	-48	_	dB
Image frequency	-		-35		dB
Adia cont changel to impage from your	$F = F_{image} + 1 \text{ MHz}$		-49	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-32	_	dB

Table 36: Receiver Characteristics - Bluetooth LE 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	-	_	-101	_	dBm
Maximum received signal @30.8% PER		_	8	_	dBm
Co-channel C/I	F = F0 MHz	_	4	_	dB
	F = F0 + 1 MHz	_	-5	_	dB
	F = F0 – 1 MHz		- 5		dB
Adjacent channel selectivity C/I	F = F0 + 2 MHz	_	-28	_	dB
	F = F0 - 2 MHz		-36	_	dB
Adjacent chainer selectivity C/1	F = F0 + 3 MHz		-36		dB
	F = F0 - 3 MHz		-38		dB
	F > F0 + 3 MHz	_	-37	_	dB
	F > F0 – 3 MHz		-41		dB
Image frequency	_	_	-37	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	_	-44	_	dB
Adjacent charmer to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-28	_	dB

Package Information 5.

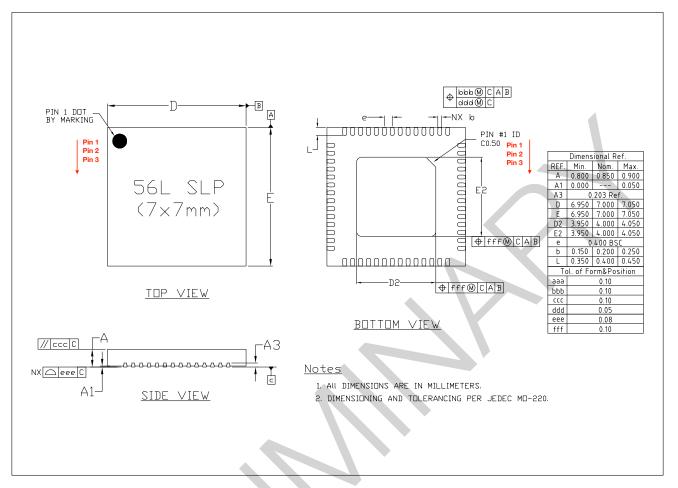


Figure 8: QFN56 (7×7 mm) Package

Note:

- The pins of the chip are numbered in an anti-clockwise direction from Pin 1 in the top view.
- For information about tape, reel, and product marking, please refer to Espressif Chip-Packing Information.

6. Related Documentation and Resources

Related Documentation

- ESP32-S3 Technical Reference Manual Detailed information on how to use the ESP32-S3 memory and peripherals.
- ESP32-S3 Hardware Design Guidelines Guidelines on how to integrate the ESP32-S3 into your hardware product.
- · Certificates
 - http://espressif.com/en/support/documents/certificates
- Documentation Updates and Update Notification Subscription http://espressif.com/en/support/download/documents

Developer Zone

- ESP-IDF and other development frameworks on GitHub.
 - http://github.com/espressif
- ESP32 BBS Forum Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.
 - http://esp32.com/
- The ESP Journal Best Practices, Articles, and Notes from Espressif folks.
 - http://blog.espressif.com/
- See the tabs SDKs and Demos, Apps, Tools, AT Firmware.
 http://espressif.com/en/support/download/sdks-demos

Products

- ESP32-S3 Series SoCs Browse through all ESP32-S3 SoCs.
 - http://espressif.com/en/products/socs?id=ESP32-S3
- ESP32-S3 Series Modules Browse through all ESP32-S3-based modules.
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Revision History

Date	Version	Release Notes
2021-10-12	v0.6.1	Updated text description
2021-09-30	v0.6	 Updated to chip revision 1 by swapping pin 53 and pin 54 (XTAL_P and XTAL_N) Updated Figure 1 Added CoreMark score in section Features Updated Section 2.8 Added data for cumulative IO output current in Table 13 Added data for Modem-sleep current consumption in Table 20 Updated data in section 4.6, 4.8, and 4.9 Updated wording throughout
2021-07-19	v0.5.1	 Added "for chip revision 0" on cover, in footer and watermark to indicate that the current and previous versions of this datasheet are for chip version 0 Corrected a few typos
2021-07-09	v0.5	Preliminary version





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